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Bib Data Sheet

CONFIRMATION NO. 7141

SERIAL NUMBER 10/828,958	FILING DATE 04/20/2004  RULE	CLASS 361	GROUP ART UNIT 2891	ATTORNEY DOCKET NO. P18609
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\*\* CONTINUING DATA \*\*\*\*\*

non CDW

\*\* FOREIGN APPLICATIONS \*\*\*\*\*

non CDW

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\*\* 06/26/2004

Foreign Priority claimed <input type="checkbox"/> yes <input checked="" type="checkbox"/> no	STATE OR	SHEETS	TOTAL	INDEPENDENT
35 USC 119 (a-d) conditions met <input type="checkbox"/> yes <input checked="" type="checkbox"/> no <input type="checkbox"/> Met after Allowance	COUNTRY	DRAWING	CLAIMS	CLAIMS
Verified and Acknowledged Examiner's Signature <i>[Signature]</i> Initials <i>CDW</i>	OR	5	20	3

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## TITLE

Method for making a semiconductor device having a high-k gate dielectric layer and a metal gate electrode

FILING FEE	FEES: Authority has been given in Paper	<input type="checkbox"/> All Fees
		<input type="checkbox"/> 1.16 Fees ( Filing )
		<input type="checkbox"/> 1.17 Fees ( Processing Ext. of